Preferred Device

Transient Voltage Suppressor Diode Array

SOT-23 Dual Common Anode Zeners for ESD Protection

These dual monolithic silicon zener diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Specification Features:

- SOT-23 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Working Peak Reverse Voltage Range 5.0 V to 12 V
- Peak Power 300 Watt (8 X 20 μs)
- Low Leakage
- Flammability Rating UL 94 V-0

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic case

FINISH: Corrosion resistant finish, easily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

Package designed for optimal automated board assembly Small package size for high density applications Available in 8 mm Tape and Reel

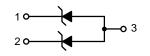
Use the Device Number to order the 7 inch/3,000 unit reel. Replace the "T1" with "T3" in the Device Number to order the 13 inch/10,000 unit reel.



ON Semiconductor®

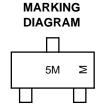
http://onsemi.com

PIN 1. CATHODE 2. CATHODE 3. ANODE





SOT-23 CASE 318 STYLE 12



5M = Device Code M = Date Code

ORDERING INFORMATION

Device	Package	Shipping		
SM05T1	SOT-23	3000/Tape & Reel		
SM12T1	SOT-23	3000/Tape & Reel		

Preferred devices are recommended choices for future use and best overall value

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Peak Power Dissipation @ 20 μs (Note 1) @ T _L ≤ 25°C		P _{pk}	300	Watts
IEC 61000-4-2 (ESD)	Air Contact		±15 ±8.0	kV
IEC 61000-4-4 (EFT)			40	А
IEC 61000-4-5 (Lightening)			12	А
Total Power Dissipation on FR-5 Board (Note 2) @ T _A = 25°C Derate above 25°C		P _D	225 1.8	mW mW/°C
Thermal Resistance Junction to Ambient		$R_{ heta JA}$	556	°C/W
Total Power Dissipation on Alumina Substrate (Note 3) @ T _A = 25°C Derate above 25°C		P _D	300 2.4	mW mW/°C
Thermal Resistance Junction to Ambient		$R_{ heta JA}$	417	°C/W
Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to +150	°C
Lead Solder Temperature - Maximum (10 Second Duration)		TL	260	°C

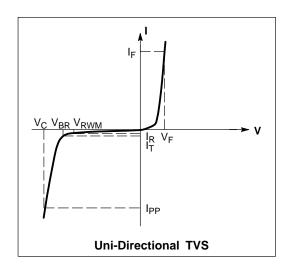
Non-repetitive current pulse per Figure 3
 FR-5 = 1.0 x 0.75 x 0.62 in.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter					
I _{PP}	Maximum Reverse Peak Pulse Current					
V _C	Clamping Voltage @ I _{PP}					
V _{RWM}	Working Peak Reverse Voltage					
I _R	Maximum Reverse Leakage Current @ V _{RWM}					
V _{BR}	Breakdown Voltage @ I _T					
I _T	Test Current					
ΘV _{BR}	Maximum Temperature Coefficient of V _{BR}					
I _F	Forward Current					
V _F	Forward Voltage @ I _F					
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}					
I _{ZK}	Reverse Current					
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}					



ELECTRICAL CHARACTERISTICS

				V _{BR} , Breakd	own Voltage		V _C @ I _{PP} =	Max I _{PP}	Typical Capacitance
		V _{RWM}	I _R @ V _{RWM}	(Vo	lts)	lτ	1 Amp	(Note 4)	(pF)
Device	Device Marking	(Volts)	(μΑ)	Min	Max	mA	(Volts)	(Amps)	Pin 1 to 3 @ 0 Volts
SM05T1	5M	5	10	6.2	7.3	1.0	9.8	17	225
SM12T1	12M	12	1.0	13.3	15.75	1.0	19	12	95

^{4.} $8 \times 20~\mu s$ pulse waveform per Figure 3

^{3.} Alumina = 0.4 x 0.3 x 0.024 in., 99.5% alumina *Other voltages may be available upon request

TYPICAL CHARACTERISTICS

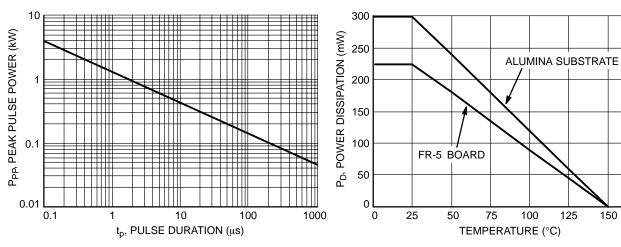


Figure 1. Non-Repetitive Peak Pulse Power versus Pulse Time

Figure 2. Steady State Power Derating Curve

150

175

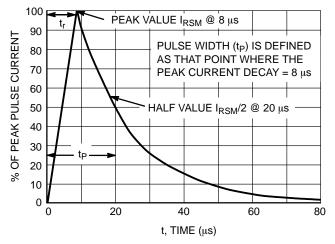


Figure 3. $8\times 20~\mu s$ Pulse Waveform

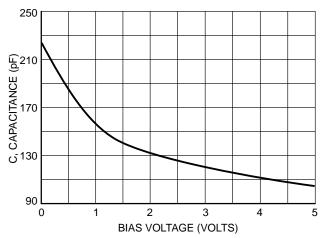


Figure 4. Typical Diode Capacitance (SM05)

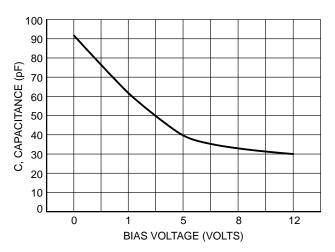


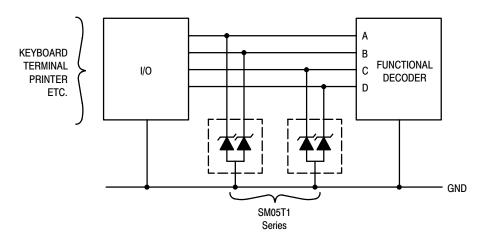
Figure 5. Typical Diode Capacitance (SM12)

TYPICAL COMMON ANODE APPLICATIONS

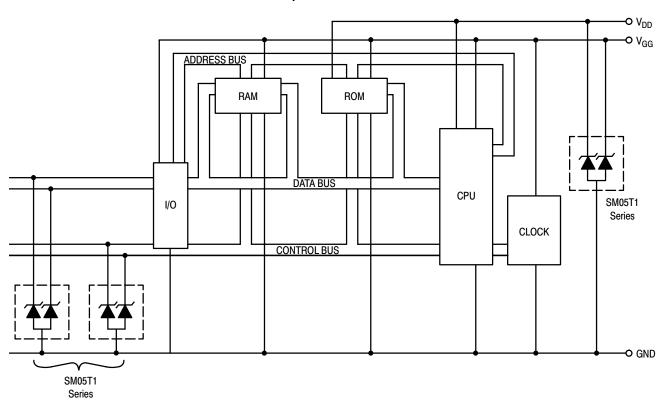
A quad junction common anode design in a SOT-23 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. Two simplified examples of TVS applications are illustrated below.

Computer Interface Protection



Microprocessor Protection

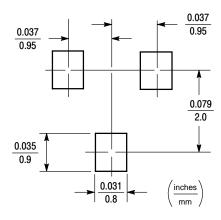


INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



SOT-23

SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by $T_{J(max)}$, the maximum rated junction temperature of the die, $R_{\theta JA}$, the thermal resistance from the device junction to ambient, and the operating temperature, T_A . Using the values provided on the data sheet for the SOT-23 package, P_D can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta, I\Delta}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature T_A of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$P_D = \frac{150^{\circ}\text{C} - 25^{\circ}\text{C}}{556^{\circ}\text{C/W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad[®]. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

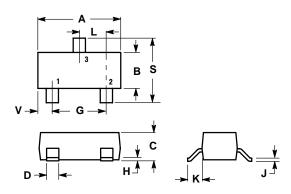
SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes.
 Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.
- * * Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

PACKAGE DIMENSIONS

SOT-23 TO-236AB CASE 318-08 **ISSUE AH**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 114-3M, 1902.

 CONTROLLING DIMENSION: INCH.

 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM LEAD THICKNESS OF BASE MATERIAL.
- 4. 318-03 AND -07 OBSOLETE, NEW STANDARD

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.1102	0.1197	2.80	3.04	
В	0.0472	0.0551	1.20	1.40	
С	0.0350	0.0440	0.89	1.11	
D	0.0150	0.0200	0.37	0.50	
G	0.0701	0.0807	1.78	2.04	
Н	0.0005	0.0040	0.013	0.100	
J	0.0034	0.0070	0.085	0.177	
K	0.0140	0.0285	0.35	0.69	
L	0.0350	0.0401	0.89	1.02	
S	0.0830	0.1039	2.10	2.64	
٧	0.0177	0.0236	0.45	0.60	

STYLE 12:

PIN 1. CATHODE

CATHODE 2.

ANODE

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